## NSN 5961-01-019-4925

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View Online at https://aerobasegroup.com/nsn/5961-01-019-4925 **Inclosure Material:** Metal **Overall Length:** Between 0.115 inches and 0.150 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Field effect **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** -15.0 gate non-trigger voltage, instantaneous and -25.0 gate to source voltage **Current Rating Per Characteristic:** 20.00 milliamperes gate current **Power Rating Per Characteristic:** 500.0 milliwatts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 00724-20-00718 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No